NSN 5961-01-092-1110

Transistor - Page 1 of 1



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Inclosure Material:

Ceramic and metal

Overall Length:

Between 0.120 inches and 0.140 inches

Overall Diameter:

0.300 inches

Mounting Facility Quantity:

1

Mounting Method:

Threaded stud

Features Provided:

Hermetically sealed case

Thread Size:

0.164 inches

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

50.0 breakdown voltage, collector-to-emitter, with base short-circuited to emitter and 4.0 breakdown voltage, emitter-to-base, collector open

Current Rating Per Characteristic:

0.50 amperes source cutoff current

Power Rating Per Characteristic:

10.0 watts small-signal input power, common-collector preset

Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

Thread Series Designator:

Unc

Terminal Type And Quantity:

4 ribbon

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

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